

electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = -30 \text{ mA}$	$I_B = 0$	(see Note 5)	BD746 BD746A BD746B BD746C	-45 -60 -80 -100		V
I_{CBO} Collector cut-off current	$V_{CE} = -50 \text{ V}$ $V_{CE} = -70 \text{ V}$ $V_{CE} = -90 \text{ V}$ $V_{CE} = -110 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	$T_C = 125^\circ\text{C}$ $T_C = 125^\circ\text{C}$ $T_C = 125^\circ\text{C}$ $T_C = 125^\circ\text{C}$	BD746 BD746A BD746B BD746C		-0.1 -0.1 -0.1 -0.1	mA
I_{CEO} Collector cut-off current	$V_{CE} = -30 \text{ V}$ $V_{CE} = -60 \text{ V}$	$I_B = 0$ $I_B = 0$		BD746/746A BD746B/746C		-0.1 -0.1	mA
I_{EBO} Emitter cut-off current	$V_{EB} = -5 \text{ V}$	$I_C = 0$				-0.5	mA
h_{FE} Forward current transfer ratio	$V_{CE} = -4 \text{ V}$ $V_{CE} = -4 \text{ V}$ $V_{CE} = -4 \text{ V}$	$I_C = -1 \text{ A}$ $I_C = -5 \text{ A}$ $I_C = -20 \text{ A}$	(see Notes 5 and 6)		40 20 5	150	
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = -0.5 \text{ A}$ $I_B = -5 \text{ A}$	$I_C = -5 \text{ A}$ $I_C = -20 \text{ A}$	(see Notes 5 and 6)			-1 -3	V
V_{BE} Base-emitter voltage	$V_{CE} = -4 \text{ V}$ $V_{CE} = -4 \text{ V}$	$I_C = -5 \text{ A}$ $I_C = -20 \text{ A}$	(see Notes 5 and 6)			-1 -3	V
h_{fe} Small signal forward current transfer ratio	$V_{CE} = -10 \text{ V}$	$I_C = -1 \text{ A}$	$f = 1 \text{ kHz}$		25		
$ h_{fe} $ Small signal forward current transfer ratio	$V_{CE} = -10 \text{ V}$	$I_C = -1 \text{ A}$	$f = 1 \text{ MHz}$		5		

NOTES: 5. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance			1.1	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$ Junction to free air thermal resistance			35.7	$^\circ\text{C}/\text{W}$

resistive-load-switching characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t_d Delay time	$I_C = -5 \text{ A}$ $V_{BE(off)} = 4.2 \text{ V}$	$I_{B(on)} = -0.5 \text{ A}$ $R_L = 6 \Omega$	$I_{B(off)} = 0.5 \text{ A}$ $t_p = 20 \mu\text{s}$, dc $\leq 2\%$		20		ns
t_r Rise time					120		ns
t_s Storage time					600		ns
t_f Fall time					300		ns

† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN
VS
COLLECTOR CURRENT

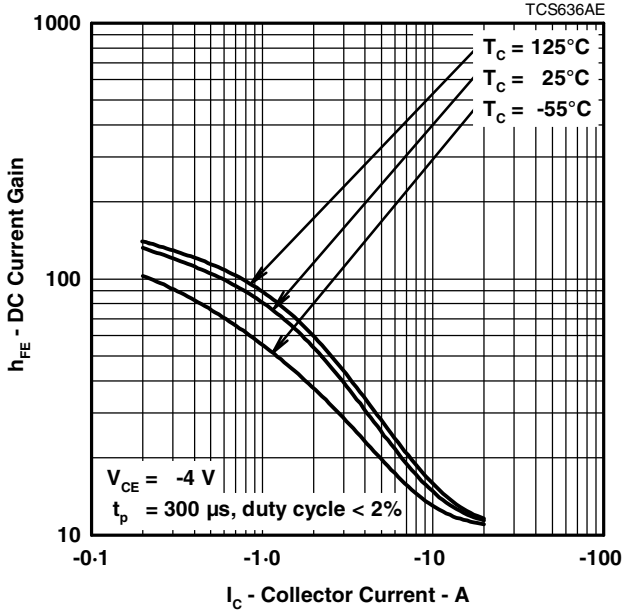


Figure 1.

COLLECTOR-EMITTER SATURATION VOLTAGE
VS
COLLECTOR CURRENT

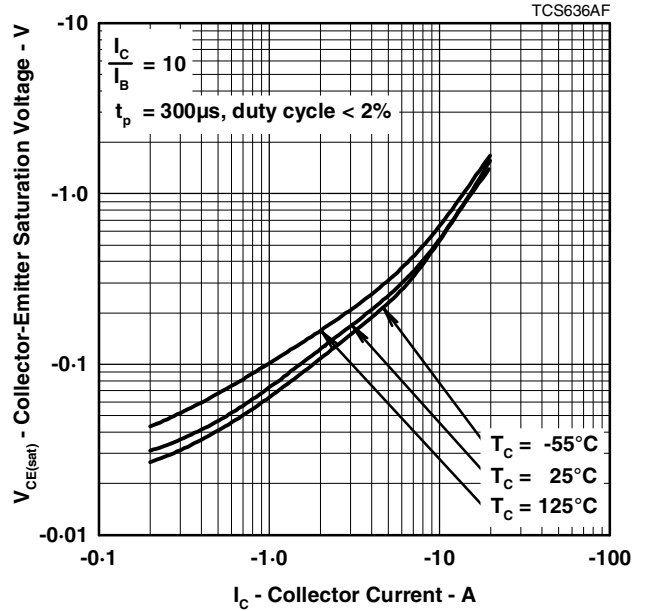


Figure 2.

MAXIMUM SAFE OPERATING REGIONS

MAXIMUM FORWARD-BIAS
SAFE OPERATING AREA

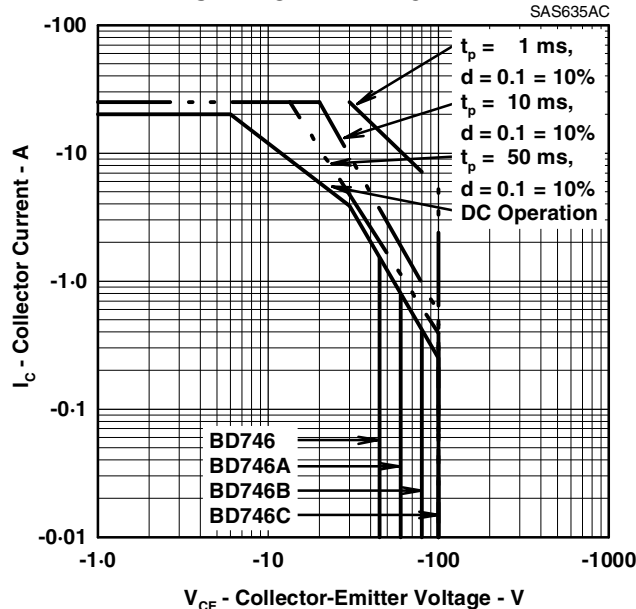


Figure 3.

PRODUCT INFORMATION

THERMAL INFORMATION

**MAXIMUM POWER DISSIPATION
vs
CASE TEMPERATURE**

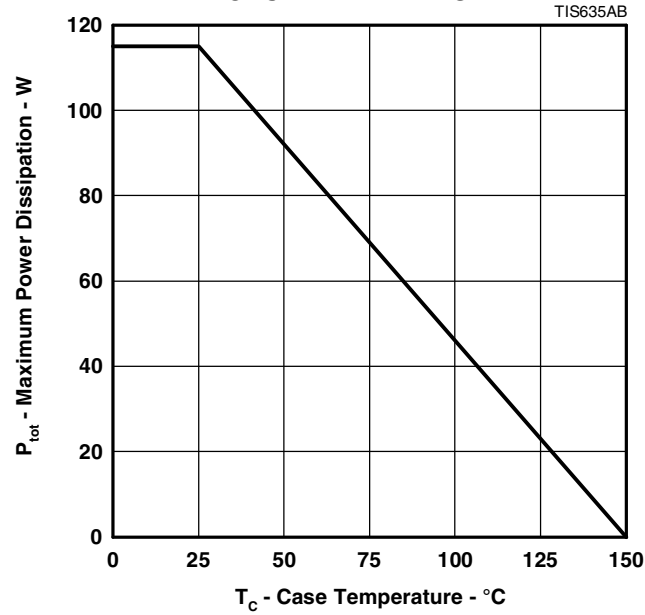


Figure 4.

Mouser Electronics

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